

BCR25FM-12LB

600V - 25A - Triac Medium Power Use R07DS0964EJ0001 Rev.0.01 Nov 28, 2012

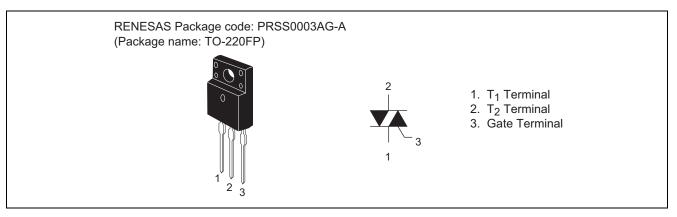
Features

- I_{T (RMS)}: 25 A
- V_{DRM}: 600 V
- Tj: 150 °C
- I_{FGTI}, I_{RGTI}, I_{RGTII}: 50 mA

Insulated Type

- Planar Passivation Type
 V = 2000 V
- V_{iso}: 2000 V

Outline



Applications

Contactless AC switch, electric heater control, light dimmer, on/off and speed control of small induction motor, on/off control of copier lamp

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
Farameter	Symbol	12	Onit
Repetitive peak off-state voltage ^{Note1}	V _{DRM}	600	V
Non-repetitive peak off-state voltage ^{Note1}	V _{DSM}	720	V

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T (RMS)}	25	A	Commercial frequency, sine full wave 360° conduction, Tc = 62° C
Surge on-state current	I _{TSM}	250	A	50 Hz sinewave 1 full cycle, peak value, non-repetitive
I ² t for fusion	l ² t	313	A ² s	Value corresponding to 1 cycle of half wave 50 Hz, surge on-state current
Peak gate power dissipation	P _{GM}	5	W	
Average gate power dissipation	P _{G (AV)}	0.5	W	
Peak gate voltage	V _{GM}	10	V	
Peak gate current	I _{GM}	2	A	
Junction Temperature	Tj	-40 to +150	°C	
Storage temperature	Tstg	-40 to +150	°C	
Mass		1.9	g	Typical value
Isolation voltage Note5	V _{iso}	2000	V	Ta = 25°C, AC 1 minute, T ₁ • T ₂ • G terminal to case



Electrical Characteristics

Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state current		I _{DRM}		—	3.0	mA	Tj = 125°C, V_{DRM} applied
				_	5.0	mA	Tj = 150°C, V_{DRM} applied
On-state voltage		V _{TM}		_	1.5	V	$Tc = 25^{\circ}C, I_{TM} = 40 A,$
							instantaneous measurement
Gate trigger voltage ^{Note2}	Ι	V_{FGTI}		_	2.0	V	$Tj = 25^{\circ}C, V_D = 6 V, R_L = 6 \Omega,$
	II	V_{RGTI}	_		2.0	V	R _G = 330 Ω
	III	V _{RGTIII}	_		2.0	V	
Gate trigger curent ^{Note2}	Ι	I_{FGTI}		_	50	mA	$Tj = 25^{\circ}C, V_D = 6 V, R_L = 6 \Omega,$
	II	I _{RGTI}			50	mA	R _G = 330 Ω
	III	I _{RGTIII}		_	50	mA	
Gate non-trigger voltage		V _{GD}	0.2	—	—	V	$Tj = 125^{\circ}C, V_{D} = 1/2 V_{DRM}$
			0.1	—	—	V	$Tj = 150^{\circ}C, V_{D} = 1/2 V_{DRM}$
Thermal resistance		R _{th (j-c)}	—	—	2.8	°C/W	Junction to case ^{Note3}
Critical-rate of rise of off-state		(dv/dt)c	10	_	—	V/µs	Tj = 125°C
commutation voltage ^{Note4}			1	_	_	V/µs	Tj = 150°C

Notes: 1. Gate open.

2. Measurement using the gate trigger characteristics measurement circuit.

3. The contact thermal resistance $R_{th \, (c\text{-}f)}$ in case of greasing is 0.5°C/W.

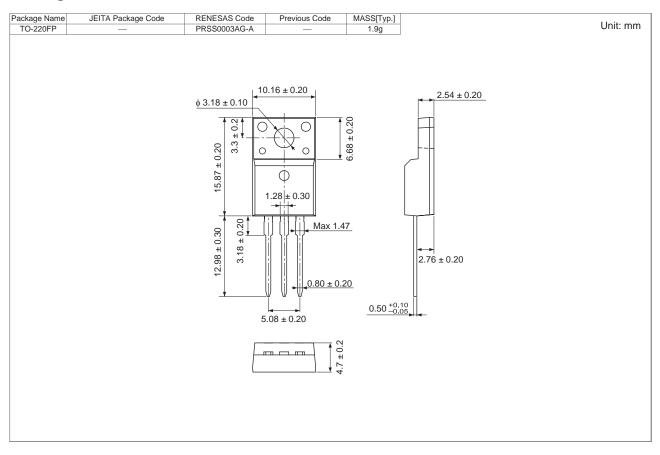
4. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.

5. Make sure that your finished product containing this device meets your safe isolation requirements. For safety, it's advisable that heatsink is electrically floating.

Test conditions	Commutating voltage and current waveforms (inductive load)				
1. Junction temperature Tj = 125°C/150°C	Supply Voltage → Time				
 Rate of decay of on-state commutating current (di/dt)c = -13 A/ms 	Main Current → Time				
3. Peak off-state voltage $V_D = 400 \text{ V}$	Main Voltage → Time (dv/dt)c V _D				



Package Dimensions



Ordering Information

Orderable Part Number	Packing	Quantity	Remark
BCR25FM-12LB#BB0	Tube	50 pcs.	Straight type
BCR25FM-12LBA8#BB0	Tube	50 pcs.	A8 Lead form

Note: Please confirm the specification about the shipping in detail.



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